

### Description

S289P is an extra high sensitive monolithic silicon epitaxial planar Darlington phototransistor in a standard T-1 (ø 3 mm) package.

The epoxy package itself is an IR filter, spectrally matched to GaAs IR emitters with  $\lambda_p$  >850nm. A plastic lens provides a wide viewing angle of ±30°.

#### Features

- Extra high radiant sensitivity
- Very low temperature drift
- Standard T–1 (ø 3 mm) package with IR filter
- Wide viewing angle  $\phi = \pm 30^{\circ}$
- Suitable for near infrared radiation

### Applications

Any applications requiring high sensitivity at low light levels e.g. Direct driving of relays and small motors Special light barriers and switches

### **Absolute Maximum Ratings**

 $T_{amb} = 25^{\circ}C$ 

Parameter	Test Conditions	Symbol	Value	Unit
Collector Emitter Voltage		V <sub>CEO</sub>	40	V
Collector Current		Ι <sub>C</sub>	0.1	А
Peak Collector Current	$t_p/T = 0.05, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	1	А
Total Power Dissipation	$T_{amb} \leq 25 \ ^{\circ}C$	P <sub>tot</sub>	185	mW
Junction Temperature		T <sub>i</sub>	100	°C
Operating Temperature Range		T <sub>amb</sub>	-55+100	°C
Storage Temperature Range		T <sub>stg</sub>	-55+100	°C
Soldering Temperature	t ≦ 5 s	T <sub>sd</sub>	260	°C
Thermal Resistance Junction/Ambient		R <sub>thJA</sub>	400	K/W

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# S289P

### Vishay Telefunken

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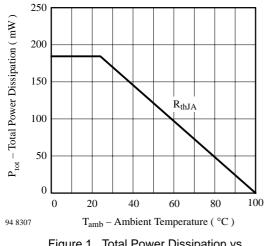


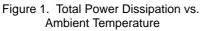
### **Basic Characteristics**

 $T_{amb} = 25^{\circ}C$ 

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Collector Emitter Breakdown Voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CE</sub>	40			V
Collector Dark Current	$V_{CE} = 20 V, E = 0$	I <sub>CEO</sub>		10	200	nA
Collector Light Current	$E_e = 0.3 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_{CE} = 5 \text{ V}$	I <sub>ca</sub>	4	15		mA
Angle of Half Sensitivity		φ		±30		deg
Wavelength of Peak Sensitivity		λρ		920		nm
Range of Spectral Bandwidth		λ <sub>0.5</sub>		8301000		nm
Collector Emitter Saturation Voltage	$E_e = 0.3 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 1 \text{ mA}$	V <sub>CEsat</sub>		0.75	1.1	V
Turn–On Time	$V_S = 5 V$ , $I_C = 5 mA$ , $R_L = 100 \Omega$	t <sub>on</sub>		40		μs
Turn–Off Time	$V_S = 5 V$ , $I_C = 5 mA$ , $R_L = 100 \Omega$	t <sub>off</sub>		50		μS

# **Typical Characteristics** ( $T_{amb} = 25^{\circ}C$ unless otherwise specified)





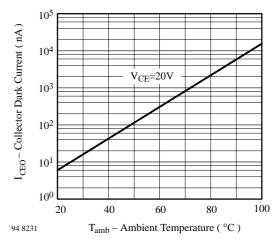


Figure 2. Collector Dark Current vs. Ambient Temperature

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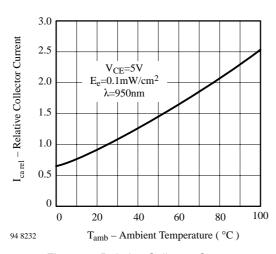


Figure 3. Relative Collector Current vs. Ambient Temperature

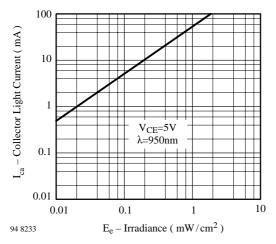
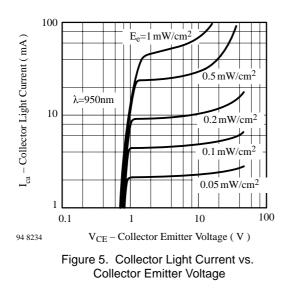


Figure 4. Collector Light Current vs. Irradiance



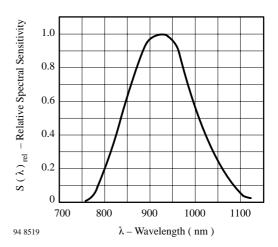


Figure 6. Relative Spectral Sensitivity vs. Wavelength

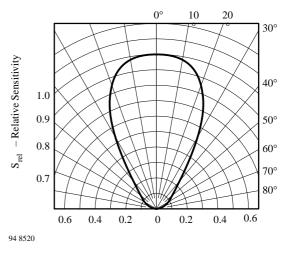
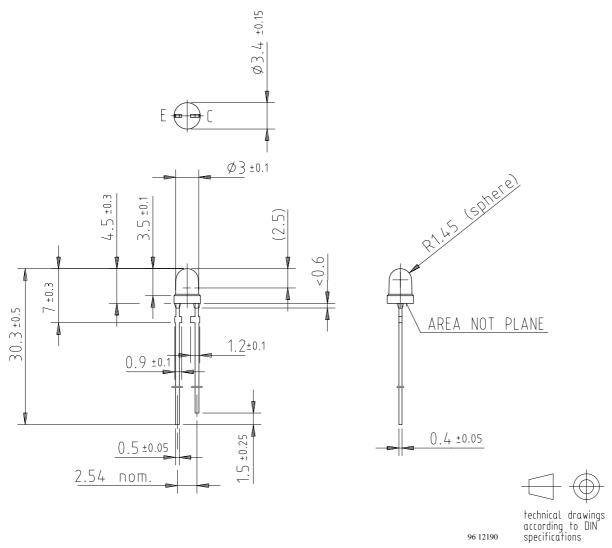


Figure 7. Relative Radiant Sensitivity vs. Angular Displacement

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### **Dimensions in mm**



S289P



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### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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